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SLLS793-JUNE 2007

FEATURES

- ESD Protection for RS-232 Bus Pins
 - ±15-kV Human-Body Model (HBM)
 - ±8-kV IEC61000-4-2, Contact Discharge
 - ±15-kV IEC61000-4-2, Air-Gap Discharge
- Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU v.28 Standards
- Operates With 3-V to 5.5-V V_{CC} Supply
- Operates up to 500 kbit/s
- Two Drivers and Two Receivers
- Low Standby Current . . . 1 μA Typ
- External Capacitors . . . 4 × 0.1 μF
- Accepts 5-V Logic Input With 3.3-V Supply
- Alternative High-Speed Pin-Compatible Device (1 Mbit/s) for TRS3222E

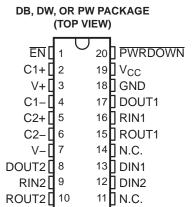
APPLICATIONS

- Battery-Powered Systems
- PDAs
- Notebooks
- Laptops
- Palmtop PCs
- Hand-Held Equipment

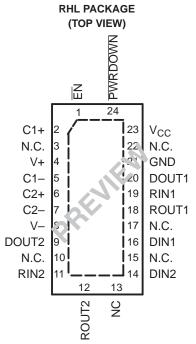
DESCRIPTION/ORDERING INFORMATION

The TRS3222E consists of two line drivers, two line receivers, and a dual charge-pump circuit with ±15-kV ESD protection pin to pin (serial-port connection pins, including GND).

The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. The device operates at typical data signaling rates up to 500 kbit/s and a maximum of 30-V/µs driver output slew rate.



N.C. - No internal connection



N.C. - No internal connection

The TRS3222E can be placed in the power-down mode by setting the power-down ($\overline{PWRDOWN}$) input low, which draws only 1 µA from the power supply. When the device is powered down, the receivers remain active while the drivers are placed in the high-impedance state. Also, during power down, the onboard charge pump is disabled; V+ is lowered to V_{CC} , and V- is raised toward GND. Receiver outputs also can be placed in the high-impedance state by setting enable (\overline{EN}) high.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH ±15-kV ESD PROTECTION

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ORDERING INFORMATION

T _A	PA	CKAGE ⁽¹⁾⁽²⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING	
	QFN – RHL	Reel of 2000	TRS3222ECRHLR	PREVIEW	
	SOIC - DW	Tube of 25 TRS3222ECDW		TRS3222EC	
	SOIC - DW	Reel of 2000	TRS3222ECDWR	TRSSZZZEC	
0°C to 70°C	SSOP – DB	Tube of 70	TRS3222ECDB	Deader.	
	330P - DB	Reel of 2000	TRS3222ECDBR	RS22EC	
	TSSOP – PW	Tube of 70	TRS3222ECPW	RS22EC	
	1330P – PW	Reel of 2000 TRS3222ECPWR		RS22EC	
	QFN – RHL	Reel of 2000	TRS3222EIRHLR	PREVIEW	
	SOIC DW	Tube of 25	TRS3222EIDW	TDC2222FI	
	SOIC – DW	Reel of 2000	TRS3222EIDWR	TRS3222EI	
–40°C to 85°C	SSOP – DB	Tube of 70	TRS3222EIDB	Degari.	
	330P - DB	Reel of 2000	TRS3222EIDBR	RS22EI	
	TCCOD DW	Tube of 70	TRS3222EIPW	DCOOFI	
	TSSOP – PW	Reel of 2000	TRS3222EIPWR	RS22EI	

⁽¹⁾ Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLES

EACH DRIVER(1)

IN	PUTS	OUTPUT
DIN	PWRDOWN	DOUT
X	L	Z
L	Н	Н
Н	Н	L

(1) H = high level, L = low level, X = irrelevant, Z = high impedance

EACH RECEIVER(1)

INPL	JTS	OUTPUT
RIN	EN	ROUT
L	L	Н
Н	L	L
X	Н	Z
Open	L	Н

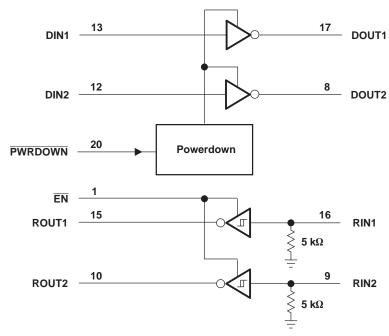
H = high level, L = low level, X = irrelevant,
 Z = high impedance (off),
 Open = input disconnected or connected driver off

⁽²⁾ For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH ±15-kV ESD PROTECTION

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LOGIC DIAGRAM (POSITIVE LOGIC)



Pin numbers are for the DB, DW, and PW packages.

Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range ⁽²⁾		-0.3	6	V
V+	Positive-output supply voltage range (2)		-0.3	7	V
V-	Negative-output supply voltage range (2)		0.3	-7	V
V+ - V-	Supply voltage difference ⁽²⁾			13	V
VI	Landration	Driver (EN, PWRDOWN)	-0.3	6	
	Input voltage range	Receiver	-25	25	V
\ /	Output voltage range	Driver	-13.2	13.2	V
Vo	Output voltage range	Receiver		V _{CC} + 0.3	V
		DB package		70	
0	Deal and the small investigation (3)(4)	DW package		58	0000
θ_{JA}	Package thermal impedance (3)(4)	PW package		83	°C/W
Ī			PREVIEW		
T _J	Operating virtual junction temperature			150	°C
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltages are with respect to network GND.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.

⁽³⁾ Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.

TRS3222E

3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH ±15-kV ESD PROTECTION

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Recommended Operating Conditions⁽¹⁾

See Figure 5

				MIN	NOM	MAX	UNIT
	Cumply yeltogo		$V_{CC} = 3.3 \text{ V}$	3	3.3	3.6	\
	Supply voltage	V _{CC} = 5 V	4.5	5	5.5	V	
\/	Driver and central high level input valtage	DIN EN DWDDOWN	V _{CC} = 3.3 V	2			\
V _{IH}	Driver and control high-level input voltage DIN, EN, PWRDOWN	$V_{CC} = 5 V$	2.4			V	
V_{IL}	Driver and control low-level input voltage	DIN, EN, PWRDOWN				0.8	٧
V_{I}	Driver and control input voltage	DIN, EN, PWRDOWN		0		5.5	٧
V_{I}	V _I Receiver input voltage					25	٧
т	Operating free air temperature		TRS3222EC	0		70	°C
T _A	Operating free-air temperature		TRS3222EI	-40		85	C

⁽¹⁾ Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V.

Electrical Characteristics(1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
I	Input leakage current (EN, PWRDOWN)			±0.01	±1	μΑ
	Supply current	No load, PWRDOWN at V _{CC}		0.3	1	mA
ICC	Supply current (powered off)	No load, PWRDOWN at GND		1	10	μΑ

⁽¹⁾ Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V. (2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

TRS3222E 3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH ±15-kV ESD PROTECTION

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DRIVER SECTION

Electrical Characteristics(1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	TEST CONDI	TEST CONDITIONS				UNIT
V_{OH}	High-level output voltage	DOUT at $R_L = 3 \text{ k}\Omega$ to GND,	DIN = GND	5	5.4		V
V_{OL}	Low-level output voltage	DOUT at $R_L = 3 \text{ k}\Omega$ to GND,	$DIN = V_{CC}$	-5	-5.4		V
I _{IH}	High-level input current	$V_I = V_{CC}$			±0.01	±1	μΑ
I _{IL}	Low-level input current	V _I at GND		±0.01	±1	μΑ	
(3)	$V_{CC} = 3.6 \text{ V}$ $V_{O} = 0 \text{ V}$			±35	±60	mA	
I _{OS}	Short-circuit output current ⁽³⁾	V _{CC} = 5.5 V	v _O = 0 v		±33	±00	ША
ro	Output resistance	V_{CC} , V+, and V- = 0 V,	$V_O = \pm 2 \text{ V}$	300	10M		Ω
Control leading a surrent		PWRDOWN = GND	$V_{CC} = 3 \text{ V to } 3.6 \text{ V},$ $V_{O} = \pm 12 \text{ V}$			±25	
I _{OZ}	Output leakage current	FWKDOWN = GND	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V},$ $V_{O} = \pm 10 \text{ V}$			±25	μΑ

Switching Characteristics⁽¹⁾

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	TEST (MIN	TYP ⁽²⁾	MAX	UNIT	
	Maximum data rate	C _L = 1000 pF, One DOUT switching,	$R_L = 3 \text{ k}\Omega$, See Figure 1	250	500		kbit/s
t _{sk(p)}	Pulse skew ⁽³⁾	C _L = 150 pF to 2500 pF, See Figure 2	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega,$		300		ns
	Slew rate,	$R_1 = 3 k\Omega$ to $7 k\Omega$,	C _L = 150 pF to 1000 pF	6		30	
SR(tr)	transition region (see Figure 1)	V _{CC} = 3.3 V	C _L = 150 pF to 2500 pF	4		30	V/µs

⁽¹⁾ Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V. (2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C. (3) Pulse skew is defined as $|t_{PLH}|$ of each channel of the same device.

 ⁽¹⁾ Test conditions are C1–C4 = 0.1 μF at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μF, C2–C4 = 0.33 μF at V_{CC} = 5 V ± 0.5 V.
 (2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.
 (3) Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one output should be shorted at a time.

TRS3222E

3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH ±15-kV ESD PROTECTION

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RECEIVER SECTION

Electrical Characteristics⁽¹⁾

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
V_{OH}	High-level output voltage	$I_{OH} = -1 \text{ mA}$	V _{CC} - 0.6	$V_{CC} - 0.1$		V
V_{OL}	Low-level output voltage	I _{OL} = 1.6 mA			0.4	V
V Parities and a found through all and to an		$V_{CC} = 3.3 \text{ V}$		1.5	2.4	V
V _{IT+}	Positive-going input threshold voltage	V _{CC} = 5 V		1.8	2.4	V
V _{IT} _	Negative-going input threshold voltage	V _{CC} = 3.3 V	0.6	1.2		V
VIT-	Negative-going input threshold voltage	V _{CC} = 5 V	0.8	1.5		V
V_{hys}	Input hysteresis (V _{IT+} - V _{IT-})			0.3		V
I_{OZ}	Output leakage current	<u>EN</u> = 1		±0.05	±10	μA
r _l	Input resistance	$V_I = \pm 3 \text{ V to } \pm 25 \text{ V}$	3	5	7	kΩ

⁽¹⁾ Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V. (2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

Switching Characteristics⁽¹⁾

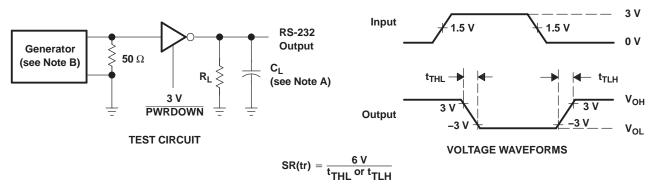
over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	TYP ⁽²⁾	UNIT
t _{PLH}	Propagation delay time, low- to high-level output	C _L = 150 pF, See Figure 3	300	ns
t _{PHL}	Propagation delay time, high- to low-level output	C _L = 150 pF, See Figure 3	300	ns
t _{en}	Output enable time	C_L = 150 pF, R_L = 3 k Ω , See Figure 4	200	ns
t _{dis}	Output disable time	C_L = 150 pF, R_L = 3 k Ω , See Figure 4	200	ns
t _{sk(p)}	Pulse skew ⁽³⁾	See Figure 3	300	ns

⁽¹⁾ Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V. (2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C. (3) Pulse skew is defined as $|t_{PLH}|$ of each channel of the same device.

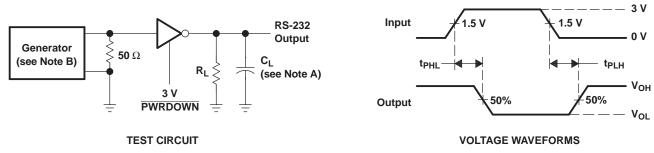
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PARAMETER MEASUREMENT INFORMATION



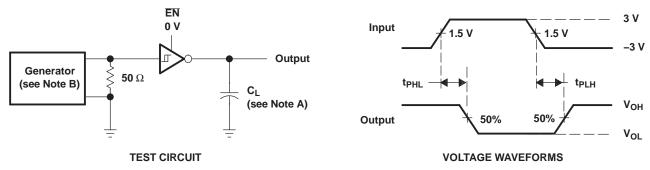
- A. C_L includes probe and jig capacitance.
- B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_0 = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.

Figure 1. Driver Slew Rate



- A. C_L includes probe and jig capacitance.
- B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_O = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.

Figure 2. Driver Pulse Skew

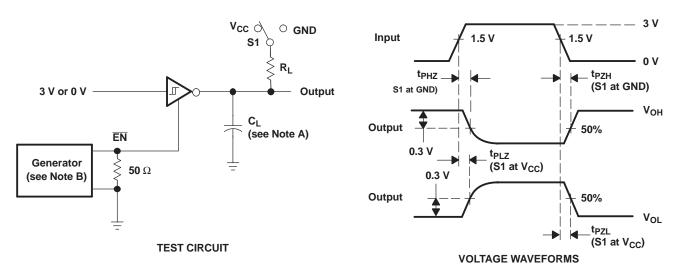


- A. C₁ includes probe and jig capacitance.
- B. The pulse generator has the following characteristics: $Z_0 = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns. $t_f \le 10$ ns.

Figure 3. Receiver Propagation Delay Times



PARAMETER MEASUREMENT INFORMATION (continued)

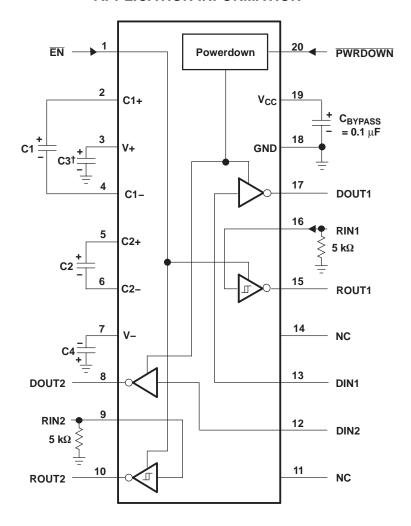


- A. C_L includes probe and jig capacitance.
- B. The pulse generator has the following characteristics: Z_0 = 50 Ω , 50% duty cycle, $t_r \le 10$ ns. $t_f \le 10$ ns.

Figure 4. Receiver Enable and Disable Times

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APPLICATION INFORMATION



 † C3 can be connected to V_{CC} or GND.

NOTES: A. Resistor values shown are nominal.

- B. NC No internal connection
 - C. Nonpolarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown.

V_{CC} vs CAPACITOR VALUES

V _{CC}	C1	C2, C3, and C4
3.3 V \pm 0.3 V	0.1 μ F	0.1 μ F
5 V \pm 0.5 V	0.047 μ F	0.33 μF
3 V to 5.5 V	0.1 μF	0.47 μ F

Figure 5. Typical Operating Circuit and Capacitor Values





5-Aug-2014

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
TRS3222ECDB	ACTIVE	SSOP	DB	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	RS22EC	Samples
TRS3222ECDBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	RS22EC	Sample
TRS3222ECDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TRS3222EC	Sample
TRS3222ECDWR	OBSOLETE	SOIC	DW	20		TBD	Call TI	Call TI	0 to 70		
TRS3222ECDWRG4	OBSOLETE	SOIC	DW	20		TBD	Call TI	Call TI	0 to 70		
TRS3222ECPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	RS22EC	Sample
TRS3222ECPWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	RS22EC	Sample
TRS3222ECPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	RS22EC	Sample
TRS3222ECPWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	RS22EC	Sample
TRS3222EIDB	ACTIVE	SSOP	DB	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	RS22EI	Sample
TRS3222EIDBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	RS22EI	Sample
TRS3222EIDW	OBSOLETE	SOIC	DW	20		TBD	Call TI	Call TI	-40 to 85		
TRS3222EIDWG4	OBSOLETE	SOIC	DW	20		TBD	Call TI	Call TI	-40 to 85		
TRS3222EIDWR	OBSOLETE	SOIC	DW	20		TBD	Call TI	Call TI	-40 to 85		
TRS3222EIDWRG4	OBSOLETE	SOIC	DW	20		TBD	Call TI	Call TI	-40 to 85		
TRS3222EIPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	RS22EI	Sample
TRS3222EIPWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	RS22EI	Sample
TRS3222EIPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	RS22EI	Sample

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.



PACKAGE OPTION ADDENDUM

5-Aug-2014

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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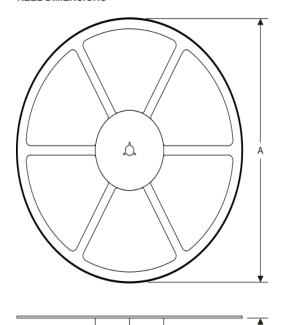
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

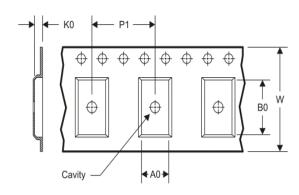
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TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TRS3222ECDBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
TRS3222ECPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
TRS3222EIDBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
TRS3222EIPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1

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*All dimensions are nominal

7 ill difficiente die Herrinia										
Device	Package Type	Package Drawing	Pins SPQ		Length (mm)	Width (mm)	Height (mm)			
TRS3222ECDBR	SSOP	DB	20	2000	367.0	367.0	38.0			
TRS3222ECPWR	TSSOP	PW	20	2000	367.0	367.0	38.0			
TRS3222EIDBR	SSOP	DB	20	2000	367.0	367.0	38.0			
TRS3222EIPWR	TSSOP	PW	20	2000	367.0	367.0	38.0			



SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



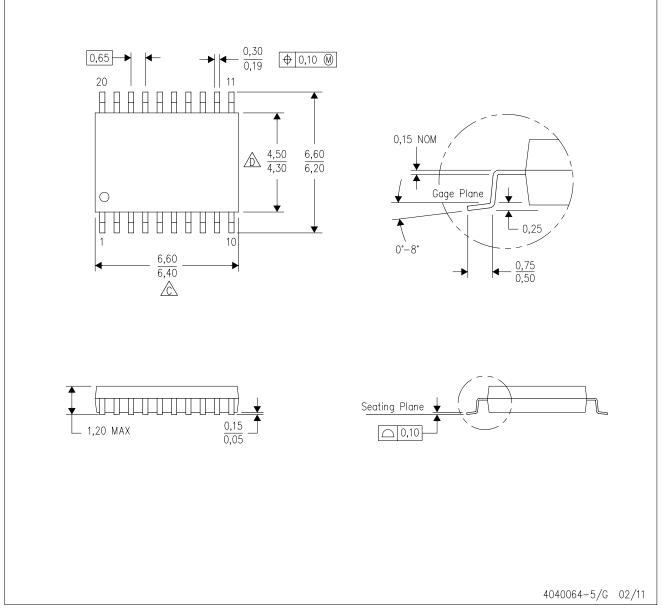
NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES:

- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

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